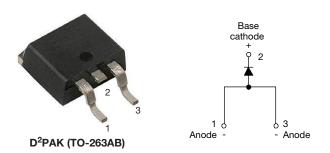


Surface Mount Fast Soft Recovery Rectifier Diode, 20 A



PRIMARY CHARACTE	RISTICS
I _{F(AV)}	20 A
V _R	600 V
V _F at I _F	1.3 V
IFSM	300 A
t _{rr}	60 ns
T _J max.	150 °C
Snap factor	0.6
Package	D ² PAK (TO-263AB)
Circuit configuration	Single

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C



- AEC-Q101 qualified
- · Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-20ETF06SLHM3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Sinusoidal waveform	20	Α					
V _{RRM}		600	V					
I _{FSM}		300	Α					
V _F	10 A, T _J = 25 °C	1.2	V					
t _{rr}	1 A, 100 A/µs	60	ns					
TJ	Range	-40 to +150	°C					

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA						
VS-20ETF06SLHM3	600	700	5						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	T _C = 97 °C, 180° conduction half sine wave	20					
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	250	Α				
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	300					
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s				
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	442	A-S				
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s				



ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	ONDITIONS	VALUES	UNITS		
Maximum forward voltage drop	V	20 A, T _J = 25 °C		1.30 V			
Maximum forward voltage drop	V_{FM}	60 A, T _J = 25 °C	v				
Forward slope resistance	r _t			12.5	mΩ		
Threshold voltage	V _{F(TO)}	T _J = 150 °C		0.9	V		
Maximum reverse leakage current		T _J = 25 °C	\/ _ rotod \/	0.1	mA		
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	$V_R = \text{rated } V_{RRM}$	5.0			

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •				
Reverse recovery time	t _{rr}	In at 20 Anu	160	ns	I _{FM} t				
Reverse recovery current	I _{rr}	I _F at 20 A _{pk} 100 Α/μs	10	Α	t _a t _b				
Reverse recovery charge	Q _{rr}	25 °C	1.25	μC	dir/ dt Q _{rr}				
Snap factor	S	Typical	0.6		I _{RM(REC)}				

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.9	°C/W			
Maximum thermal resistance junction to ambient (PCB mount)	R _{thJA} (1)		40	-C/VV			
Soldering temperature	T _S		260	°C			
Approximate weight			2	g			
Approximate weight			0.07	oz.			
Marking device		Case style D ² PAK (TO-263AB)	20ETF	06SH			

Note

 $^{^{(1)}}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W.

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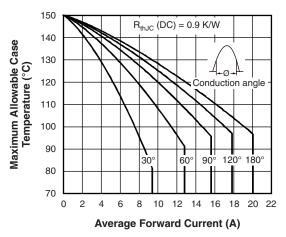


Fig. 1 - Current Rating Characteristics

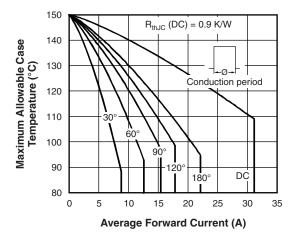


Fig. 2 - Current Rating Characteristics

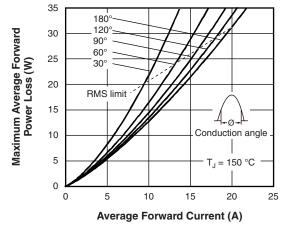


Fig. 3 - Forward Power Loss Characteristics

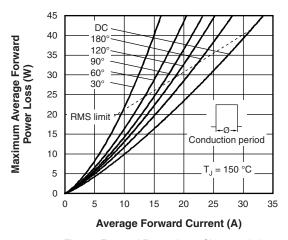


Fig. 4 - Forward Power Loss Characteristics

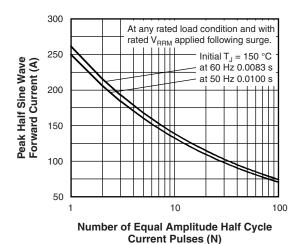


Fig. 5 - Maximum Non-Repetitive Surge Current

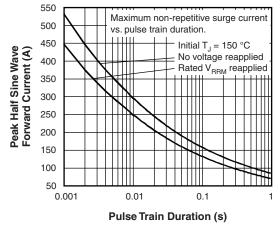


Fig. 6 - Maximum Non-Repetitive Surge Current



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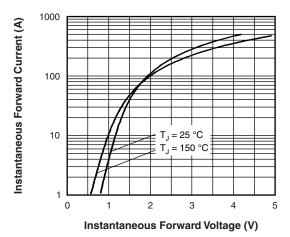


Fig. 7 - Forward Voltage Drop Characteristics

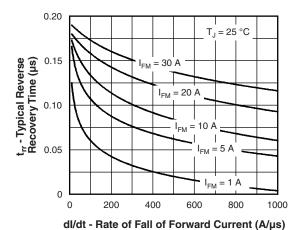


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C

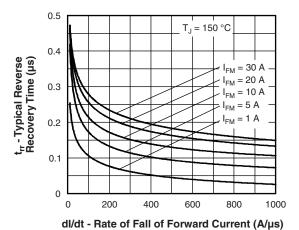
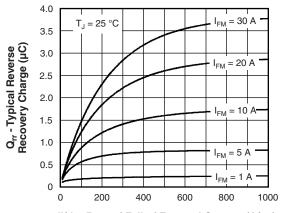
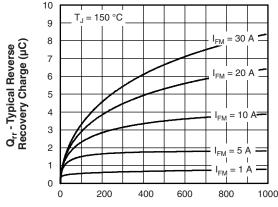


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \, ^{\circ}\text{C}$



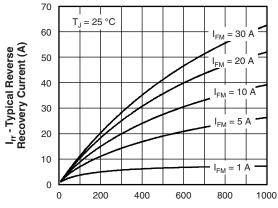
dl/dt - Rate of Fall of Forward Current (A/µs)





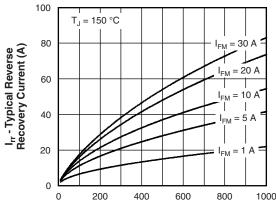
dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 12 - Recovery Current Characteristics, $T_J = 25 \, ^{\circ}\text{C}$



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

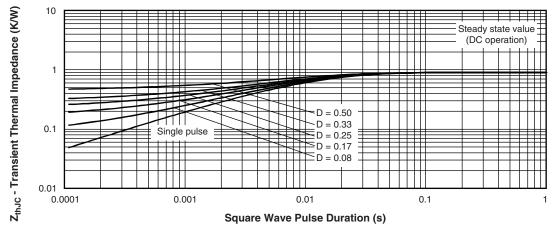
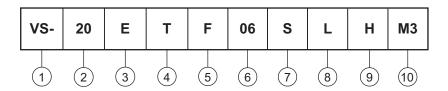


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (20 = 20 A)
- 3 Circuit configuration:

E = single diode

- 4 Package:
 - $T = D^2PAK$
- 5 Type of silicon:

F = fast soft recovery rectifier

- 6 Voltage code x 100 = V_{RRM} ----- 06 = 600 V
- 7 S = surface mountable
- 8 L = tape and reel (left oriented), for different orientation contact factory
- 9 H = AEC-Q101 qualified
- 10 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

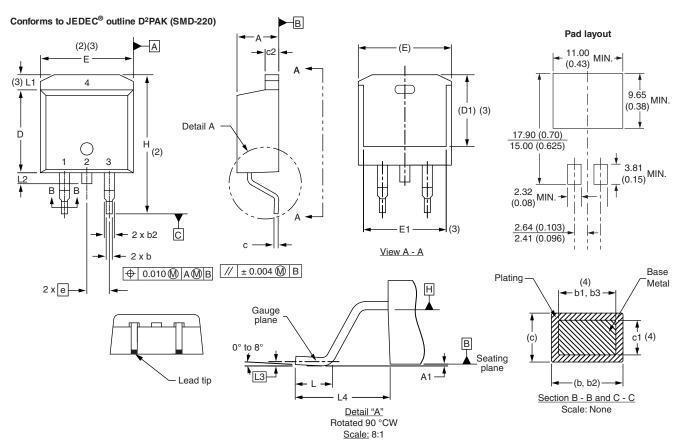
ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-20ETF06SLHM3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95046</u>					
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96317				



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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